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SIEMENS

IC for Inductive Proximity Switches with Short-Circuit Protection

TCA 505 BG

Bipolar IC

Pb-free lead plating; RoHS compliant

Features

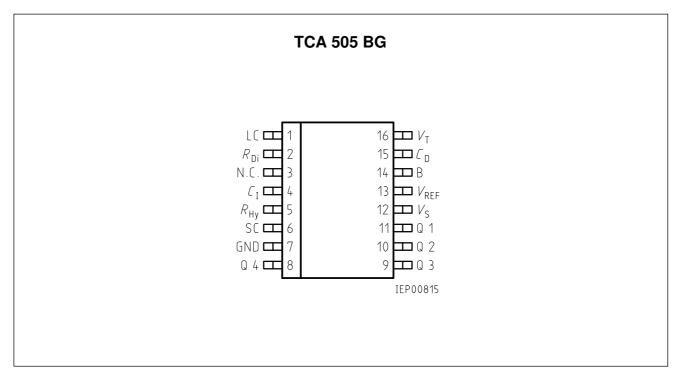
- Wide supply voltage of 3.1 to 4.5 V and 4 to 40 V
- Low current consumption of less than 0.8 mA
- Integrated output stage for up to 60 mA output current
- Short-circuit and overload protection of output stages and external components
- Temperature response of the IC compensates that of the coil
- High noise immunity
- High switching frequencies up to 5 kHz
- Useful extra functions
- Suitable for two-wire AC proximity switches
- Temperature range − 40 to 110 °C

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PG-DSO-16-1	

Туре	Ordering Code	Package
TCA 505 BG	Q67000-A8341	PG-DSO-16-1 (SMD)
TCA 505 B	Q67000-A8342	Chip

Besides its basic functions (oscillator, demodulator and threshold switch), the bipolar monolithic IC TCA 505 B includes a number of useful extra functions that enable high-grade, inductive proximity switches to be designed for an attractive price/performance ratio and with space savings.

Compared to earlier ICs for inductive proximity switches temperature drift, noise immunity and the switching frequency of the IC have been improved.



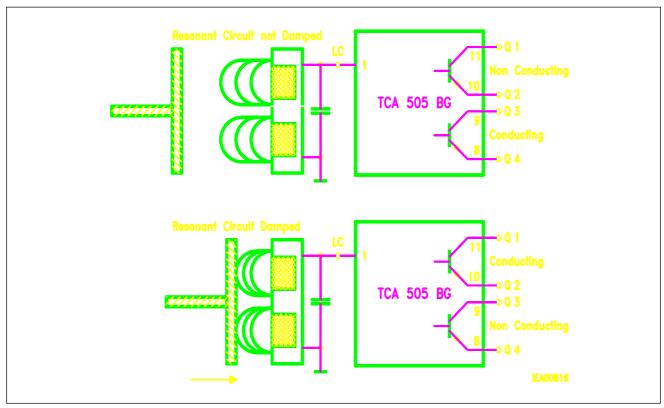
Pin Configurations

(top view)

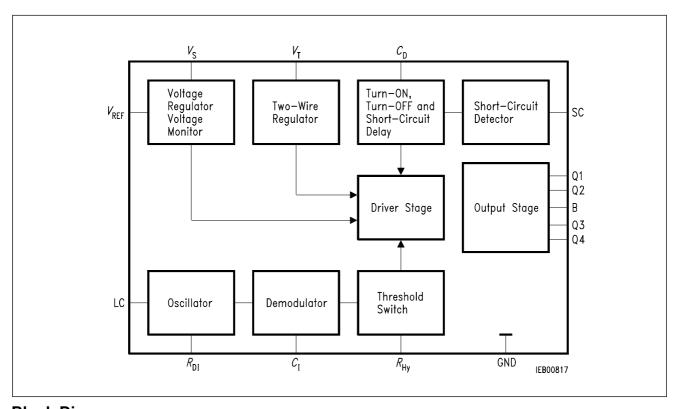
Pin Definitions and Functions

Pin	Symbol	Function
1	LC	Oscillator
2	RDi	Distance
3	N.C.	Not connected
4	Cı	Integrating capacitance
5	RHy	Hysteresis
6	SC	Short-circuit detector
7	GND	Ground
8	Q4	Output
9	Q3	Output
10	Q2	Output
11	Q1	Output
12	Vs Vs	Supply voltage
13	V_{REF}	Reference voltage
14	В	Base Output Transistors
15	CD	Turn-ON delay / Short-circuit delay
16	V_{T}	Two-wire regulator

Functional Description and Application



Operation Schematic



Block Diagram

Functional Description

This circuit is used to design inductive proximity switches. The resonant circuit of the LC oscillator is implemented with an open half-pot ferrite and a capacitor in parallel (pin LC). If a metallic target is moved closer to the open side of the half-pot ferrite, energy is drawn from the resonant circuit and the amplitude of the oscillation is reduced accordingly. This change in amplitude is transmitted to a threshold switch by means of a demodulator and triggers the outputs (see operation schematic).

By means of an external distance resistor on the oscillator (pin R_{Di}) it is possible to set the switching distance within wide limits, the optimal distances being 0.1 to 0.6 of the diameter of the half-pot ferrite, although both of these parameters can be exceeded. The circuit also enables the setting of a path hysteresis by switching of the external distance resistor via pin R_{Hy} (see application circuit 1).

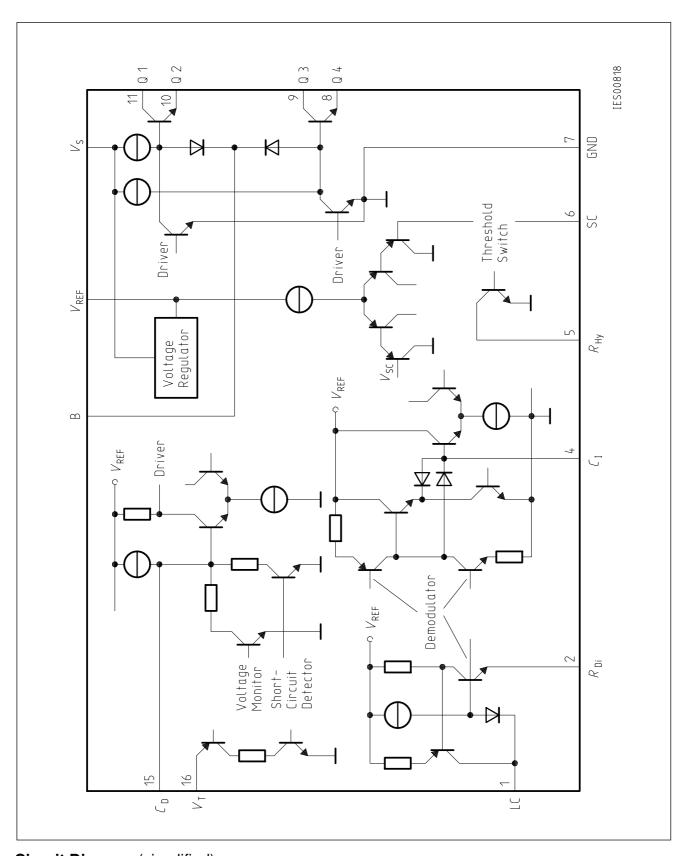
There are two antiphase output stages (Q1 / Q2 and Q3 / Q4) for max. 50 mA. The output transistors are driven in a floating state thus providing the user with optimal flexibility for evaluation of the output signals. It is therefore possible to use the output transistors either as emitter follower, open-collector, as a current source or in push-pull operation. When pin B is connected to V_{REF} , Q2 and Q4 can be used between 0 V and V_{REF} . The maximum base voltage of the output transistors can be set on pin B. If B is connected to V_{REF} , any constant current up to 50 mA can be set on the outputs by means of resistors on Q2 or Q4 (see application circuits 2 and 3).

Q1 through Q4 and also additional external output transistors can be protected against destruction by short-circuit or overload. This is the purpose of pin SC which turns off the output transistors periodically in the presence of overload.

By means of a capacitor on C_D it is possible to set the response delay and the turn-OFF time of short-circuit protection. The same capacitor also defines the turn-ON delay of the output stages when the supply voltage is applied, whereby the output stages are inhibited during buildup of the oscillator. Finally C_D produces a turn-OFF delay of the output stages to prevent the turn-ON delay from running its full length at brief voltage dips on V_S .

A switching regulator is incorporated for the voltage supply of the circuit when it is used as a two-wire AC proximity switch, and this is activated when pin V_T is connected to V_S . The circuit has a stabilized voltage of approx. 2.9 V that is brought out on pin V_{REF} .

Supply-voltage range: The operating range in normal operation is between 4 and 40 V. If pin V_{REF} is connected to V_{S} , the circuit is operating between 3.1 and 4.5 V. In this case, however, V_{REF} is no longer internally stabilized, i.e. the analog IC functions depend on the operating voltage.



Circuit Diagram (simplified)

Pin Functions

Pin 1; LC

The resonant circuit of the proximity switch is connected between LC and ground.

Pin 2; RDi

A resistor between this pin and ground sets the current in the oscillator circuit. The greater the value of the resistor, the smaller is the current feed from the oscillator into the resonant circuit and the greater therefore is the switching distance. The greater the Q of the resonant circuit, the greater is the value of the distance resistor necessary for setting a certain switching distance.

Pin 4; *C*₁

 C_1 can remain open; if high noise immunity is to be achieved however, this pin should be provided with a series RC element (R_1 , C_1). If pin C_D is not used, a correctly dimensioned RC element on this pin will also prevent any erroneous pulses on the output when the supply voltage is turned on (**see application circuit 1**).

Pin 5; R_{Hy}

Depending on the status of the circuit, $R_{\rm Hy}$ will be high-impedance or low-impedance to ground (open collector). If the distance resistance (see $R_{\rm Di}$) is split into two resistors $R_{\rm Di}$ and $R_{\rm Hy}$, a distance hysteresis can be set by means of $R_{\rm Hy}$. If series hysteresis is applied, $R_{\rm Hy}$ is connected in series with $R_{\rm Di}$ or shorted. If parallel hysteresis is applied, $R_{\rm Hy}$ is connected in parallel with $R_{\rm Di}$ or made high-impedance (see application circuit 1).

Pin 6; SC

SC serves for short-circuit sensing in the output circuit that is to be protected. The current can be sensed referred to ground or V_S . The current sensing is made by a dedicated resistor in the output circuit. For a voltage drop ≥ 0.3 V across V_S and SC or across ground and SC, all outputs are turned off after the turn-OFF delay (brief glitches on the outputs or the charging of line capacitances therefore do not trigger the short-circuit protection). After a pause about 200 times the turn-off delay, the outputs turn-ON again. If the short-circuit is still present, the turn-OFF cycle will start up anew.

Both the internal output stages and externally connected output stages can be protected against sustained short-circuits or overload.

A limiting of the output current is an externally connected output stage during the turn-off delay must be ensured. Normally the current limiting by the β of the output transistor is sufficient, meaning that no further circuit devices are called for (**see application circuits**). The outputs Q1 to Q4 are already internally protected against overcurrent so that, in the case of a short-circuit, the current will not exceed 250 mA.

In order to prevent thermal overloads, the current-conducting output is to be connected to pin SC (see application circuit 4).

Pins 8, 9, 10, 11; Outputs Q1, Q2, Q3, Q4

Q1 is the open collector, Q2 the open emitter of one output transistor, Q3 the open collector and Q4 the open emitter of the second output transistor in antiphase with the first output transistor (**see operation schematic**). Q1 and Q3 or Q2 and Q4 can be connected in parallel as required. The function of the outputs is ensured when the emitter potential of the output transistors (Q2, Q4) is between 0 V and the voltage on pin B. If B is not connected, the operating range of Q2 and Q4 extends to approx. $V_S - 2$ V. For current setting on the outputs, **see pin B**.

Pin 12; *V*s

Outputs Q1 through Q4 are inhibited as long as the voltage on V_S is below approx. 3.6 V. They are enabled between approx. 3.6 and 4 V, the basic function of the circuit is then ensured. During the turn-ON and turn-OFF of V_S there are consequently no undesirable static states. The operating data and characteristics apply upwards from 4 V. See pin C_D for the avoidance of erroneous pulses during oscillator buildup.

Pin 13; V_{REF}

The internal stabilized voltage of the IC of approx. 2.9 V appears on this pin. A capacitor can be connected between V_{REF} and ground to improve the noise immunity of the overall circuit function. If V_{REF} is connected to V_{S} , it is possible to operate the circuit in a supply- voltage range of 3.1 through 4.5 V. In this case V_{REF} is no longer stabilized. The analog functions of the circuit e.g. switching distance, however, are then dependent on the supply voltage.

Pin 14; B

This pin serves for limiting the base voltage of the internal output-stage transistors. If this pin is connected to V_{REF} for example, it is possible to set a constant output current ($I_{\text{Q}} = V_{\text{REF}}$ / external resistor) that is independent of the supply voltage by means of an external resistor across Q2 (or Q4) and ground (watch out for power dissipation!).

Pin 15; C_D

A capacitor on this pin delays the activation of the outputs after the supply voltage is applied (turn-ON delay). In this way erroneous pulses are prevented on the output during buildup of the oscillator.

If V_S falls to less than 3.6 to 4 V, the outputs are not inhibited until after a turn-OFF delay time, this also being determined by C_D . In this way the delayed turn-ON operation described above is suppressed if there are just short glitches (voltage dips) on V_S . This is of particular advantage for large core diameters, because in such cases a relativity long turn-ON delay has to be selected and the delayed twin-on operation would otherwise be activated each time there was a brief voltage dip.

The capacitor C_D also sets the turn-off delay and the pause duration in short-circuit operation. The sample / pause ratio is approx. 1:200 (**see pin SC**).

If these functions can be dispensed with, C_D can remain open.

Pin 16; *V*_T

If this pin is connected to $+ V_S$, the supply voltage of the IC (when used as a two-wire proximity switch) can be generated by switching the outputs. The quiescent current can then be kept low. This mode is primarily suitable for AC switches with power supply by phase-control.

The switching of the outputs is made in a V_s range of 6 to 8 V. At 8 V the outputs are turned on, until V_s falls to 6 V. At 6 V the outputs are inhibited, until V_s again reaches 8 V. In this mode V_s should not exceed 14 V or fall below 4 V.

Absolute Maximum Ratings

 $T_A = -40 \text{ to } 110 \text{ }^{\circ}\text{C}$

Parameter	Symbol	Limi	t Values	Unit	Test Condition		
		min. max.					
Supply voltage	Vs	- 0.3	42	V			
Output voltages B open B connected	Va1; Va3 Va2; Va4 Va2; Va4	- 1 - 1 - 1	41 Vs + 1 VB	V V V	V_{Q2} ; $V_{Q4} \le V_{S}$ V_{Q2} ; V_{Q1} ; V_{Q4} $< V_{Q3}$		
Output currents	IQ1; IQ3 - IQ2; - IQ4	0	60 60	mA mA	does not apply to shortcircuit		
Voltage on V_{\top}	V _T	- 0.3	14	V			
Current on VREF	- IREF	0	100	μА			
Voltage on SC	V _{SC}	0	<i>V</i> s	V			
Current from RDi	$-I_{ m RDi}$	0	2	mA			
Current to R _{Hys}	I_{RHy}	0	2	mA			
Voltage on B	V_{SB}	- 0.3	<i>V</i> s	V			
Storage temperature	Tstg	- 55	110	°C			
Thermal resistance (system - air)	Rth SA		110	K/W	PG-DSO-16-1		
Junction temperature	T _i T _j		110 150	°C	max. 70.000 h		
Capacitor	Cv		50	nF	applies to short- circuit at the TCA 505 B only		
Operating Range							
Supply voltage	Vs Vs	4 3.1	40 4.5	V	$V_{REF} = V_{S}$		
Ambient temperature	TA	- 40	110	°C			
Distance and Hysteresis resistance R_{Di} and R_{Hy} in series R_{Di} and R_{Hy} parallel	RDi R Hy R Di/ R Hy	300 0 300		52			
Output voltage on Q2, Q4 B open B connected	Va2; Va4 Va2; Va4	- 0.3 - 0.3	Vs - 2 V _B	V			

Only the circuitry provided for passive components may be connected to pins LC, R_{Di} , C_{I} , C_{D}

Characteristics

4 V \leq VS \leq 40 V; TA = - 40 to 110 $^{\circ}$ C

Parameter	Symbol	Limit Values			Unit	Test	
		min.	typ. max.			Circuit	
Power Supply (V s)							
Current consumption Normal mode (S1 = S2 = OFF) Two-wire operation S1 = ON, S2 = OFF $4 \text{ V} \le V_S \le 12 \text{ V}$	Is Is		550 625	740 840	μ Α μ Α	1 1	
Turn-ON threshold (outputs active) S1 = OFF	V _{TON1}		3.64	4	V	1	
Turn-OFF threshold (outputs disabled) S1 = OFF	VTOFF1	3.0	3.6		V	1	
Hysteresis V _{TON1} – V _{TOFF1} S1 = OFF	ΔV Hy1		40		mV	1	
Oscillator (LC, RDi)	1						
Oscillator frequency	<i>f</i> osc			3	MHz	1	
Oscillator amplitude	Aosc		8.0		$V_{\sf pp}$	1	
Demodulator, Threshold Switch	(C_{I},R_{Hy})						
Threshold on C_1	V_{CI}		2		V	1	
Hysteresis on C	VHyCl		0.8		V	1	
Current in C	<i>I</i> cı		7		μΑ	1	
Current from C ₁	- <i>I</i> cı		6		μΑ	1	
Switching frequency C1 < 50 pF	Æ		5		kHz	1 (L = 70 μH	
Reference Voltage (V_{REF}); Base (Output Transi	stors					
Reference voltage $I_{REF} = 0$ to 100 μ A	V_{REF}	2.65	2.9	3.10	V		
Offset voltage $V_B = V_{Q2}$, 4 $V_B = V_{REF}$; I_{Q2} , 4 = 5 mA	V_{OB}		110	155	mV	1	

Characteristics (cont'd) 4 V $\leq V_s \leq$ 40 V; $T_A = -40$ to 110 °C

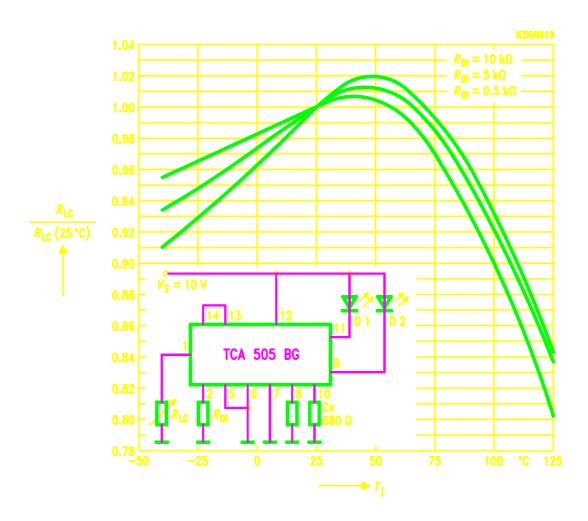
Parameter	Symbol	Limit Values			Unit	Test
		min.	typ.	max.		Circuit
Two-Wire Regulator (V_{T})						
Turn-ON threshold (outputs active) S1 = ON	Vton2	6.7	8	9.3	V	1
Turn-ON threshold (outputs disabled) S1 = ON	Vtoff2	5.0	6	7.0	V	1
Hysteresis $V_{\text{TON2}} - V_{\text{TOFF2}}$, S1 = ON	ΔНу 2	1.6	2	2.4	V	1
Turn-ON, Turn-OFF and Short-Circu	uit Delay (d	Сь)				
Turn-ON delay S1 = OFF	<i>t</i> DON	0.49	0.65	0.82	ms/nF	2
Turn-OFF delay S1 = OFF; $V_S \ge 3.6 \text{ V}$	<i>t</i> va	17.0	25	34.0	μs/nF	2
Shortcircuit turn-off delay S1 = OFF	<i>t</i> sc	1.70	2.5	3.40	μs/nF	2
Shortcircuit pause S1 = OFF	<i>t</i> P	0.36	0.5	0.65	ms/nF	2
Outputs (Q1, Q2, Q3, Q4)						
Residual voltage Q1-Q2, Q3-Q4 SQ2 0-1 = ON, SQ4 0-1 = ON S1 = OFF	V_{QRes}					
$I_Q = 5 \text{ mA}$	V_{QR}		0.10	0.14	V	1
$I_{Q} = 60 \text{ mA}$ $I_{Q} = 60 \text{ mA}$	$V_{ m QR}$ $V_{ m QR}$	Vs - 2.2	0.5 <i>V</i> s –1.8	0.99	V	1 1
Reverse current on Q1, 3	I_{QR}			10	μА	
Residual current on Q2, 4*) Q2, 4 conducting but Q1, 3 open	<i>I</i> Qres			50	μΑ	1
In case of short-circuit output current	$I_{ extsf{QSC}}$		300	500	mA	1

Shortcircuit Detector (SC)

Trigger level ref. to Vs, S1 = OFF	Vscs	0.255	0.3	0.345	V	1
Trigger current S1 = OFF	<i>I</i> scs			30	μА	1
Trigger level ref. to ground S1 = OFF	Vsco	0.255	0.3	0.345	٧	1
Trigger current S1 = OFF	- Isco			6	μА	1

Diagrams

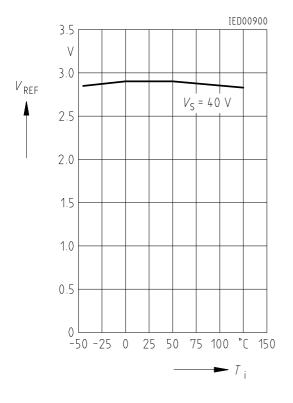
Temperature Response of Switching Point



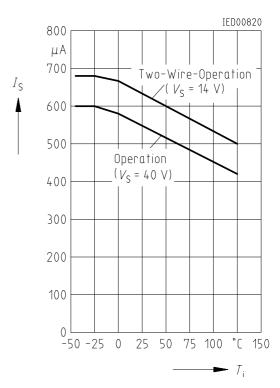
Resistor R_{LC} is set in each case so that the TCA 505 B just switches from D2 to D1. In this way the TCA 505 B, together with a suitably dimensioned resonant circuit, can form a proximity switch that exhibits a very good temperature coefficient (\pm 2.5 %) over the entire temperature range and without any kind of extra external wiring.

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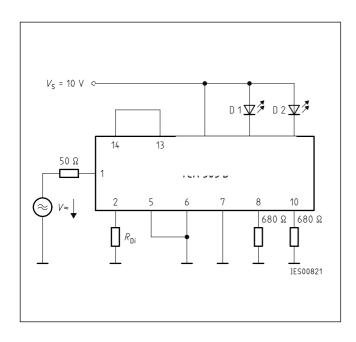
Diagrams Reference Voltage versus Junction Temperature *T*_j

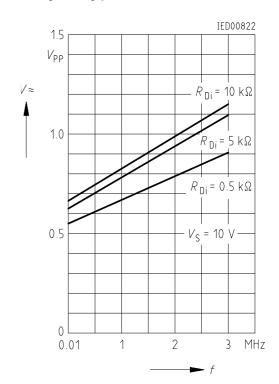


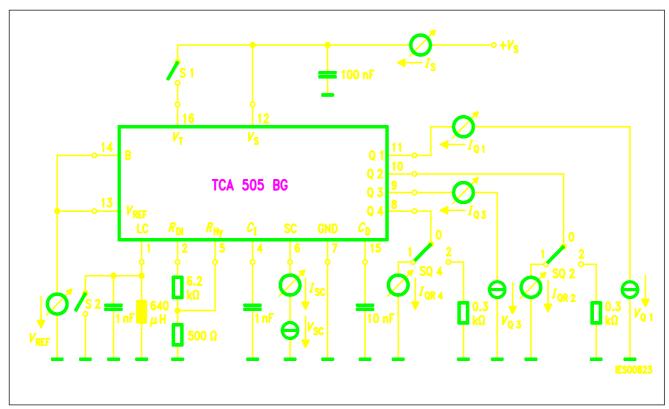
Current Consumption versus Junction Temperature T_i



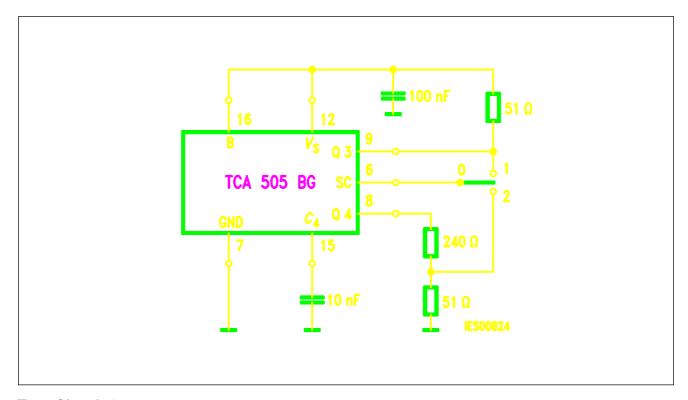
Switching Amplitude versus Frequency f



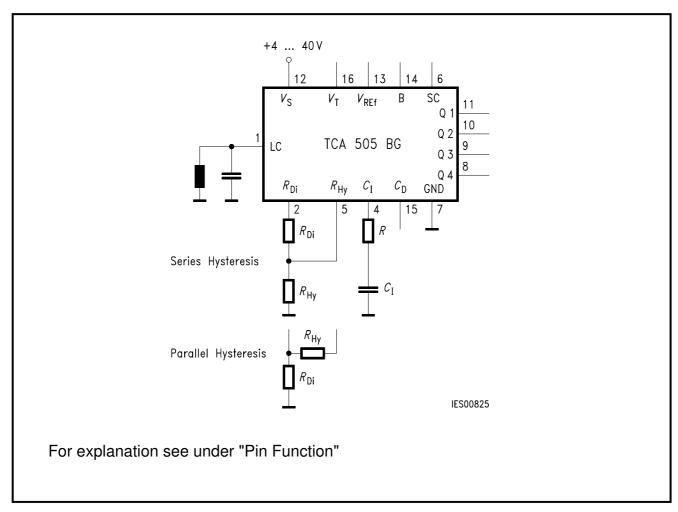




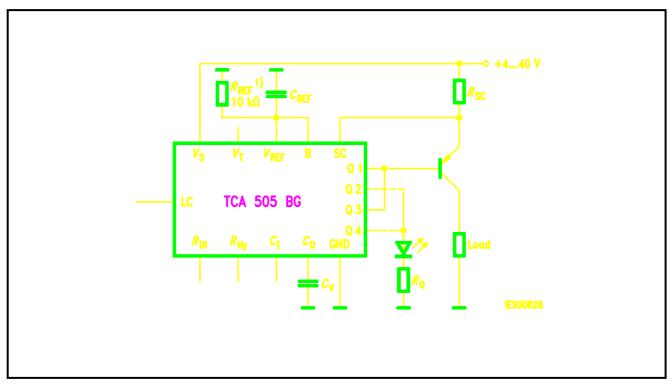
Test Circuit 1



Test Circuit 2



Application Circuit 1 Input Circuitry (Use of pins LC, $R_{\rm Di}, R_{\rm Hy}, C_{\rm I}$)



Application Circuit 2 Output Circuitry (Use of pins V_{REF} , B, SC, Q1 through Q4, C_{D})

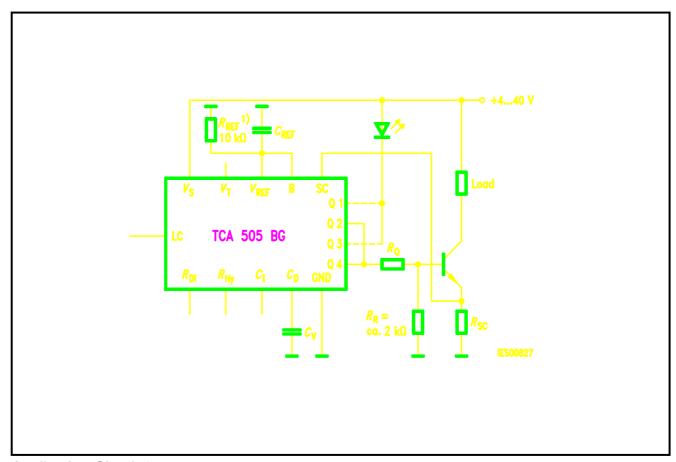
P-switch, short-circuit-proof, LED indicator, configurable as normally closed or normally open

Short-circuit-current sampling:
$$Rsc = \frac{0.3 \text{ V}}{\text{max. load current}}$$

Constant base current: 1)
$$R_Q = \frac{2.9 \text{ V} - V_{\text{LED}}}{\text{max. base current}}$$

For dimensioning of C_D see characteristics. C_D is usually between 1 and 10 nF. Filtering of V_{REF} is for noise immunity. C_{REF} can be 10 nF for example.

When $I_Q > 10$ mA, a resistor R_{REF} on pin V_{REF} will improve the constant current operation.



Application Circuit 3

Output Circuitry (Use of pins VREF, B, SC, Q1 through Q4, CD)

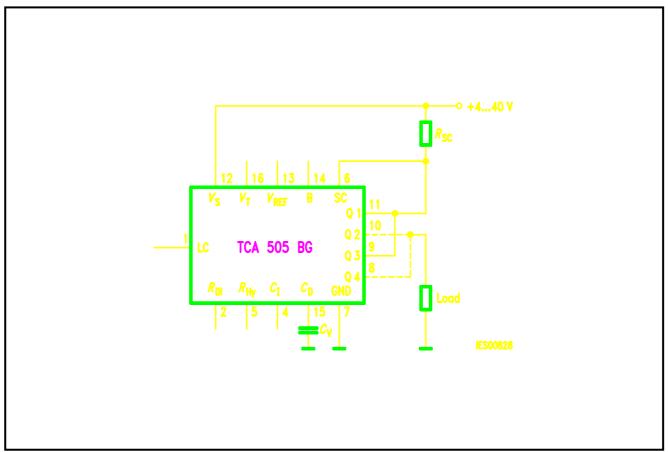
N-switch, short-circuit-proof, LED indicator, configurable as normally closed or normally open

Short-circuit-current sampling:
$$R_{SC} = \frac{0.3 \text{ V}}{\text{max. load current}}$$

Constant base current: 1)
$$R_Q = \frac{2 \text{ V}}{\text{max. base current } + I_{RR}}$$

For dimensioning of C_D see characteristics. C_D is usually between 1 and 10 nF. Filtering of V_{REF} is for noise immunity. C_{REF} can be 10 nF for example. R_{REF} serves for discharging residual current of outputs Q2, 4.

When $I_Q > 10$ mA, a resistor R_{REF} on pin V_{REF} will improve the constant current operation.



Application Circuit 4

Output Circuitry (Use of pins SC, Q1 to Q4, CD)

P-switch, short-circuit-proof, configurable as normally closed or normally open

Short-circuit-current sampling:
$$R_{SC} = \frac{0.3 \text{ V}}{\text{max. load current}}$$

During the sampling time, the short-circuit current within the IC is limited to a maximum of 250 mA. For dimensioning of C_V , **see characteristics**. C_D is usually between 1 and 10 nF.